

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|---|---|------------------|---------|------------------|
| L1 | 675 | ((438/144,60,75,for.213).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2004/11/17 10:01 |
| L2 | 0 | ((Junction near field near effect near transistor JFET) with (metal near oxide near silicon MOS MOSFET) with (bipolar)) and 1 | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2004/11/17 10:01 |
| L3 | 868 | ((438/60,75,76,77,78,79,144,145,146,147,148,for.213).CCLS.) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2004/11/17 10:03 |
| L4 | 0 | 3 and transisstor with (amplify\$3 amplifi\$5) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2004/11/17 10:05 |
| L5 | 29 | 3 and transistor with (amplify\$3 amplifi\$5) | US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2004/11/17 10:05 |